



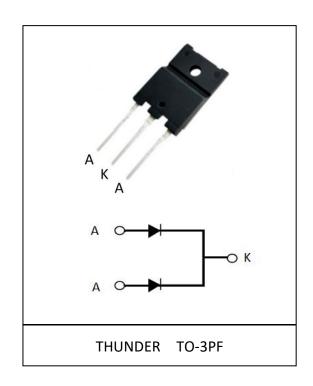
Thunder High Power Products

FRED Ultrafast Soft Recovery Diode, 60A

Features:

- Ultrafast Recovery
- 175°C operating junction temperature
- High frequency operation
- Low power loss, less RFI and EMI
- Low I_R value
- High surge capacity
- Epitaxial chip construction

Product Summary	
VR	600 V
IF(AV)	2*30A
trr	28 ns



Description/Applications

These diodes are optimized to less losses and EMI/RFI in high frequency power conditioning system. The soft recovery behavior of the diodes offers the need as snubber in most applications. These devices are ideally suited for HF welding power converters and other applications where the switching losses are not significant portion of the total losses.

Absolute Maximum Ratings

Parameter	Symbol	Test Conditions	Values	Units
Repetitive peak reverse voltage	Vrrm		600	V
Continuous forward current	lf(AV)	Tc =110°C	60	
Single pulse forward current	IFSM	Tc =25°C	540	А
Maximum repetitive forward current	IFRM	Square wave, 20kHZ	110	
Operating junction	Тј		175	°C
Storage temperatures	Tstg		-55 to +175	°C

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THR60U06DE



Electrical characteristics (Ta=25°C unless otherwise specified)

Parameter	Symbol	Test Conditions	Min	Тур.	Max.	Units
Breakdown voltage	VBR,	Ir=100μA	600			
Blocking voltage	V_R	IK-100PA	000			
Forward voltage (per die)		IF=30A		1.30	1.60	V
	VF	IF=30A, Tj =125°C		1.05	1.40	
Reverse leakage		VR= VRRM Tj=150°C, VR=600V			20	
current (per die)	l _R				200	μΑ
Reverse recovery		I _F =0.5A, I _R =1A, I _{RR} =0.25A I _F =1A,V _R =30V, di/ <i>dt</i> =200A/us		35	50	
time	trr			28	40	ns
Reverse recovery time	trr	I _F =30A,V _R =300V, d _{IF} /dt = -200A/μs ,T _J =25°C		34		ns
Maximum Reverse Recovery Current	IRM			3		Α
Reverse Recovery Charge	Qrr			118		nC
Reverse recovery time	trr	I _F =30A,VR =300V, d _{IF} /dt = -200A/μs ,T _J =125°C		108		ns
Maximum Reverse Recovery Current	IRM			7		А
Reverse Recovery Charge	Qrr			465		nC

Thermal characteristics

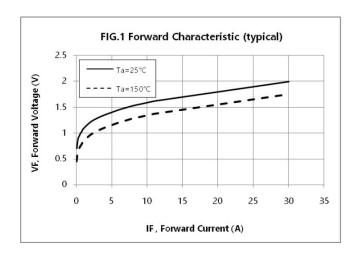
Paramter	Symbol	Тур	Units
Junction-to-Case	R _{θJC}	0.75	°C/W

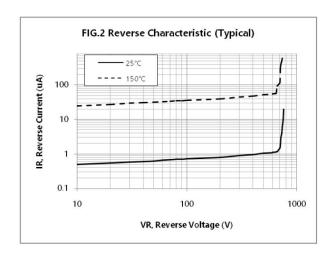
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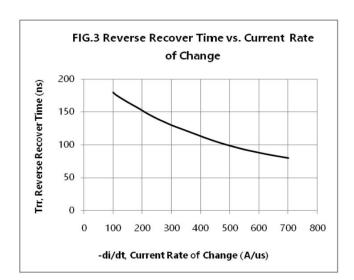


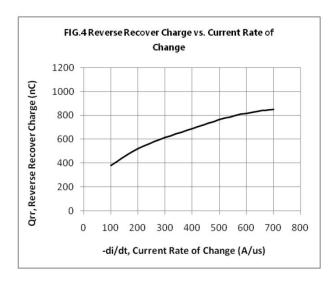


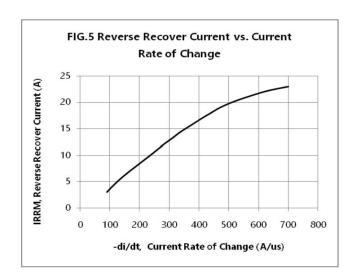
Electrical performance (typical)

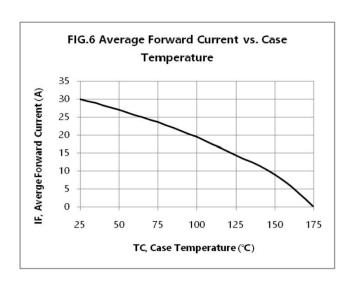












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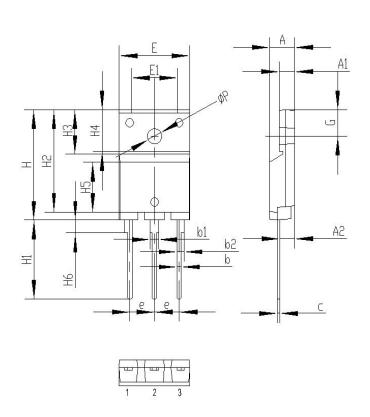






Package Information

TO-3PF PACKAGE



Symbol	Dimensions	(millimeters)
Symbol	Min.	Max.
Α	5.30	5.70
A1	3.25	3.65
A2	3.15	3.55
b	0.80	1.20
b1	1.85	2.15
b2	1.45	1.75
С	0.40	0.80
е	5.25	5.65
Е	15.4	15.8
E1	10.0	10.4
Н	22.5	23.2
H1	16.0	17.0
H2	21.2	21.6
H3	9.10	9.50
H4	8.55	8.95
H5	10.20	10.60
H6	2.55	2.85
G	5.30	5.70
ΦР	3.00	3.40

Notice

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